D. Thin Film Process Technology 분과

2017년 2월 15일 (수), 10:10-11:40 Room A (에메랄드, 2층)

[WA2-D] 2D Materials and Devices

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WA2-D-1 10:10-10:25	Two-Dimensional SnS _x Growth by Sulfurization of Atomic Layer Deposited SnO _x Jung Joon Pyeon ^{1,2} , In-Hwan Baek ¹ , Chong-Yun Kang ^{1,2} , and Seong Keun Kim ¹ ¹ Center for Electronic Materials, Korea Institute of Science and Technology, ² KU-KIST Graduate School of Converging Science and Technology, Korea University
WA2-D-2 10:25-10:40	Alignment of Solution-Processed Single Walled Carbon Nanotubes via Dielectropherosis with Removable Carbon Electrodes Min Young Jeong, Geun Woo Baek, Seung Yeob Kim, Jong Ik Baek, and Sung Hun Jin Department of Electronic Engineering, Incheon National University
WA2-D-3 10:40-10:55	Enhanced High Photoconductivity Gain MoS ₂ Hetero Junction Photo Sensor TFT with Transparent Electrodes Junghak Park ¹ and Sanghun Jeon ² ¹ Department of Applied Physics, Korea University, ² Department of Display and Semiconductor Physics, Korea University
WA2-D-4 10:55-11:10	Multi-Layer WSe ₂ Field Effect Transistor with Improved Carrier-Injection Contact by Using Oxygen Plasma Treatment Won-Mook Kang, SungTae Lee, In-Tak Cho, Tae Hyung Park, Hyeonwoo Shin, Cheol Seong Hwang, Changhee Lee, Byung-Gook Park, and Jong-Ho Lee Department of ECE and ISRC, Seoul National University
WA2-D-5 11:10-11:25	A Comparative Study on Photo-Sensitive Inverters Based on Amorphous Si and MoS ₂ Thin Film Transistors Seng Gi Seo, Jae Hyun Ryu, Geun Woo Baek, and Sung Hun Jin Department of Electronic Engineering, Incheon National University
WA2-D-6 11:25-11:40	The Effect of Interfacial Transition Metal Oxide Layer Grown by Oxygen Plasma on Tungsten Diselenide Field-Effect Transistor Sang Min Kim, Tae Kwang Kim, So Myeong Shin, Hye Won Du, Seon Yeong Kim, Min Ho Siong, Seung Jun Kim, and Sun Ae Seo Department of Physics, Sejong University